NSN 5961-01-375-0803

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View Online at https://aerobasegroup.com/nsn/5961-01-375-0803 **Inclosure Material:** Metal **Overall Length:** Between 0.965 inches and 0.985 inches **Overall Height:** Between 0.230 inches and 0.260 inches Overall Width: Between 0.225 inches and 0.241 inches **End Application:** 6625-01-286-3566 **Mounting Facility Quantity: Internal Configuration:** Junction contact-double emitter **Mounting Method:** Threaded hole **Cubic Measure:** 0.060 cubic inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 16.0 collector to emitter voltage/static/base open and 36.0 collector to base voltage/static/emitter open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter and 150.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: